

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	451	(257/19.ccls. 257/47.ccls. 257/85.ccls. 257/183.ccls. 257/189.ccls. 438/197.ccls. 438/235.ccls. 438/309.ccls. 438/452.ccls.) and @pd>"20050504"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/07 11:00
S2	1232	257/565.ccls. not (257/19.ccls. 257/47.ccls. 257/85.ccls. 257/183.ccls. 257/189.ccls. 438/197.ccls. 438/235.ccls. 438/309.ccls. 438/452.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 19:58
S3	163	257/584.ccls. not (257/19.ccls. 257/47.ccls. 257/85.ccls. 257/183.ccls. 257/189.ccls. 438/197.ccls. 438/235.ccls. 438/309.ccls. 438/452.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 20:10
S4	662	257/586.ccls. not (257/584.ccls. 257/19.ccls. 257/47.ccls. 257/85.ccls. 257/183.ccls. 257/189.ccls. 438/197.ccls. 438/235.ccls. 438/309.ccls. 438/452.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 20:11
S5	1861	S2 or S4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 20:11
S6	59	S5 and (insulating adj substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 20:58
S7	2	(("20040036078") or ("20050040432") or ("20040036078")).PN	US-PGPUB; USPAT	OR	OFF	2006/01/03 21:00
S8	1	("20030160266").PN.	US-PGPUB; USPAT	OR	OFF	2006/01/03 21:00
S9	0	(("insulatingadjsubstrate)andheterojunctionand(bipolaradjtransistor)").PN	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/07 08:38
S10	2077	(insulating adjsubstrate) and heterojunction and (bipolar adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/07 08:41

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S11	456	(insulating adj substrate) and heterojunction and (bipolar adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/07 08:41
S12	57	S11 and (metal with (insulating adj substrate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/07 09:32
S13	8	S11 and (common adj collector)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/07 09:32
S14	0	("2004/0036078"):URPN.	USPAT	OR	ON	2006/01/07 09:47
S15	1	"20040036078"	DERWENT	OR	ON	2006/01/07 09:54
S16	1	2004-207103:NRAN	DERWENT	OR	ON	2006/01/07 09:55
S17	1	(S04-B04A and U11-C18B4 and U12-A01A4 and U12-A01B3 and U12-A02B3 and V04-T01).epi.	DERWENT	OR	ON	2006/01/07 10:43
S18	1	(S04-B04A and U11-C18B4 and U12-A\$ and V04-T01).epi.	DERWENT	OR	ON	2006/01/07 10:40
S19	1	(S04-B04A and U11-C\$ and U12-A\$ and V04-T01).epi.	DERWENT	OR	ON	2006/01/07 10:39
S20	1	(S04-B04A and V04-T01).epi.	DERWENT	OR	ON	2006/01/07 10:39
S21	1	(S04-B04A and U11-C18B4 and U12-A01A4 and U12-A01B3 and U12-A02B3).epi.	DERWENT	OR	ON	2006/01/07 10:39
S22	1	(S04-B04A and U11-C18B4 and U12-A\$).epi.	DERWENT	OR	ON	2006/01/07 10:39
S23	2	(U11-C18B4 and U12-A\$ and V04-T01).epi.	DERWENT	OR	ON	2006/01/07 10:42
S24	2	(U11-C\$ and U12-A\$ and V04-T01).epi.	DERWENT	OR	ON	2006/01/07 10:42
S25	3	(S04-\$ and U11-\$ and U12-\$ and V04-\$).epi.	DERWENT	OR	ON	2006/01/07 10:43
S26	820	(metal adj layer) near ((insulating adj substrate) ceramic)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/07 11:02
S27	0	S26 and (common adj collector)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/07 11:02

S28	0	S26 and heterojunction and (bipolar adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/07 11:03
S29	15	S26 and (bipolar adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/07 11:42
S30	3	((("6262696") or ("6567138") or ("5693956"))).PN.	US-PGPUB; USPAT	OR	OFF	2006/01/07 11:42